

Excellent Integrated System Limited

Stocking Distributor

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Vishay Semiconductor/Diodes Division MBR1645

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>

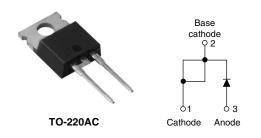




MBR16.. Series

Vishay High Power Products

Schottky Rectifier, 16 A



PRODUCT SUMMARY				
I _{F(AV)}	16 A			
V _R	35/45 V			
V _F at 16 A at 25 °C	0.63 V			
I _{RM}	40 mA at 125 °C			

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- · Designed and qualified for industrial level

DESCRIPTION

The MBR16.. Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	16	A		
V _{RRM}		35/45	V		
I _{FSM}	$t_p = 5 \ \mu s \ sine$	1800	A		
V _F	16 Apk, T _J = 125 °C	0.57	V		
TJ	Range	- 65 to 150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	MBR1635	MBR1645	UNITS
Maximum DC reverse voltage	V _R	35	45	V
Maximum working peak reverse voltage	V _{RWM}	33	40	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	T _C = 134 °C, rated V _R		16	А
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse Surge applied at rated load co	Following any rated load condition and with rated V _{RRM} applied ndition half wave	1800 150	A
Non-repetitive avalanche energy	E _{AS}	single phase, 60 Hz T _J = 25 °C, I _{AS} = 3.6 A, L = 3.7 mH		24	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3.6	А



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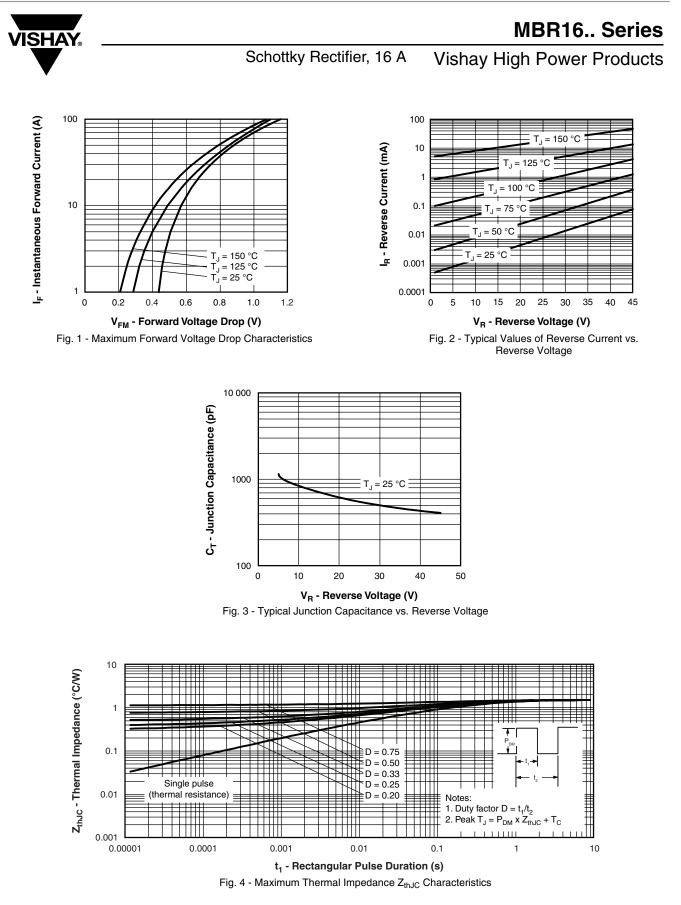
ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM} ⁽¹⁾	16 A	T _J = 25 °C	0.63	v
			T _J = 125 °C	0.57	
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.2	mA
		T _J = 125 °C		40	
Maximum junction capacitance	CT	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		1400	pF
Typical series inductance	L _S	Measured from top of terminal to mounting plane 8.0		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/μs		V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperatu	Maximum junction temperature range			- 65 to 150	°C	
Maximum storage temperatu	re range	T _{Stg}		- 65 to 175	JC	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	1.50	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	0/10	
Approximate weight				2	g	
				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf ⋅ cm	
	maximum			12 (10)	(lbf ⋅ in)	
Marking device				MBR	MBR1635	
			Case style TO-220AC (JEDEC)	MBR	MBR1645	







Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of MBR1645 - DIODE SCHOTTKY 45V 16A TO220AC

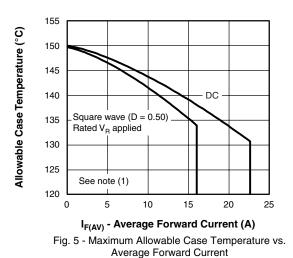
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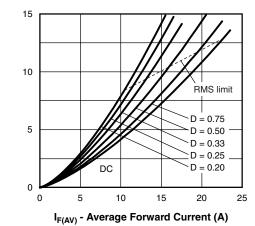
Average Power Loss (W)

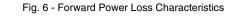
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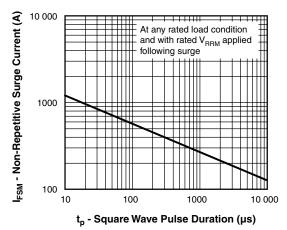


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

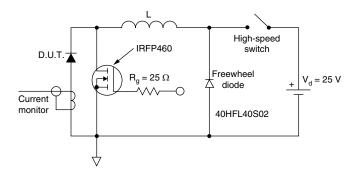


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = Rated V_R applied$



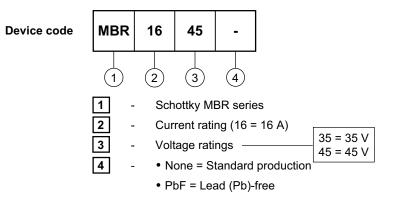


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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95221				
Part marking information	http://www.vishay.com/doc?95224			





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Vishay

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